

SOT-23 Plastic-Encapsulate Transistors

BC856A,B TRANSISTOR (PNP)

BC857A, B,C

BC858A, B,C

FEATURES

- Ideally suited for automatic insertion
- For Switching and AF Amplifier Applications

MAXIMUM RATINGS (T_A=25°C unless otherwise noted)



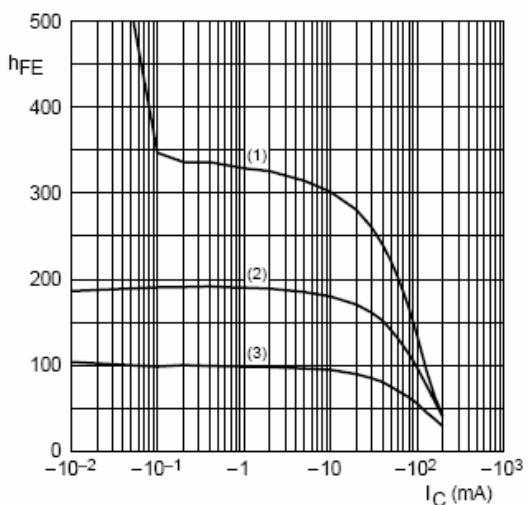
Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage		
	BC856	-80	V
	BC857	-50	
	BC858	-30	
V _{CEO}	Collector-Emitter Voltage		
	BC856	-65	V
	BC857	-45	
	BC858	-30	
V _{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current –Continuous	-0.1	A
P _C	Collector Power Dissipation	200	mW
T _J	Junction Temperature	150	°C
T _{stg}	Storage Temperature	-65-150	°C

ELECTRICAL CHARACTERISTICS (T_{amb}=25°C unless otherwise specified)

Parameter		Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage	BC856	V _{CBO}	I _C = -10µA, I _E =0	-80		
	BC857			-50		V
	BC858			-30		
Collector-emitter breakdown voltage	BC856	V _{CEO}	I _C = -10mA, I _B =0	-65		
	BC857			-45		V
	BC858			-30		
Emitter-base breakdown voltage		V _{EBO}	I _E = -1µA, I _C =0	-5		V
Collector cut-off current	BC856	I _{CBO}	V _{CB} = -70 V , I _E =0		-0.1	
	BC857		V _{CB} = -45 V , I _E =0			µA
	BC858		V _{CB} = -25 V , I _E =0			
Collector cut-off current	BC856	I _{CEO}	V _{CE} = -60 V , I _B =0		-0.1	
	BC857		V _{CE} = -40 V , I _B =0			µA
	BC858		V _{CE} = -25 V , I _B =0			
Emitter cut-off current		I _{EBO}	V _{EB} = -5 V , I _C =0		-0.1	µA
DC current gain	BC856A, 857A,858A	h _{FE}	V _{CE} = -5V, I _C = -2mA	125	250	
	BC856B, 857B,858B			220	475	
	BC857C,BC858C			420	800	
Collector-emitter saturation voltage		V _{CE(sat)}	I _C =-100mA, I _B = -5 mA		-0.5	V
Base-emitter saturation voltage		V _{BE(sat)}	I _C = -100mA, I _B = -5mA		-1.1	V
Transition frequency		f _T	V _{CE} = -5 V, I _C = -10mA f=100MHz	100		MHz
Collector capacitance		C _{ob}	V _{CB} =-10V, f=1MHz		4.5	pF

Typical Characteristics

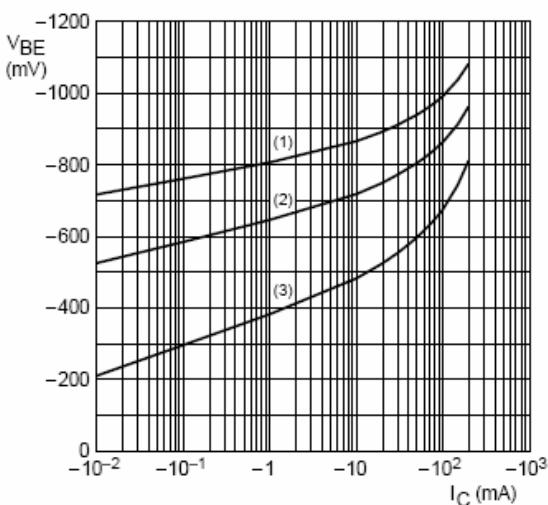
BC856;BC857;BC858



BC857A; $V_{CE} = -5$ V.

- (1) $T_{amb} = 150^\circ C$.
- (2) $T_{amb} = 25^\circ C$.
- (3) $T_{amb} = -55^\circ C$.

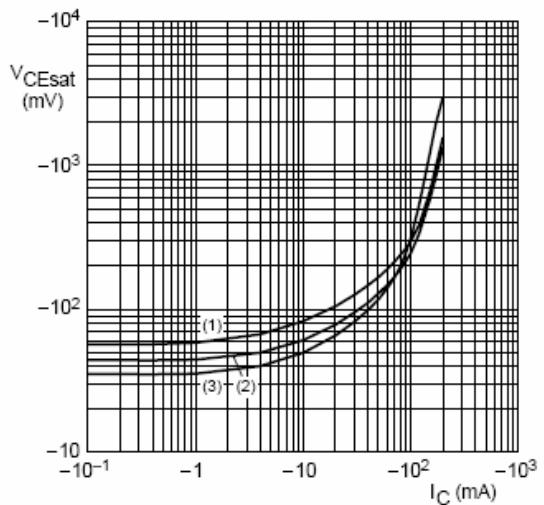
Fig.2 DC current gain as a function of collector current; typical values.



BC857A; $V_{CE} = -5$ V.

- (1) $T_{amb} = -55^\circ C$.
- (2) $T_{amb} = 25^\circ C$.
- (3) $T_{amb} = 150^\circ C$.

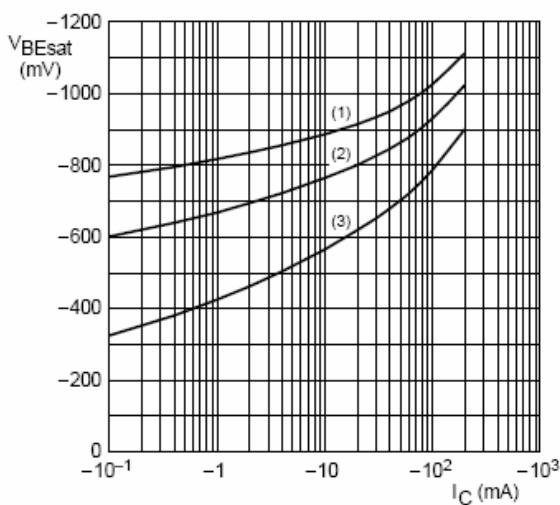
Fig.3 Base-emitter voltage as a function of collector current; typical values.



BC857A; $I_C/I_B = 20$.

- (1) $T_{amb} = 150^\circ C$.
- (2) $T_{amb} = 25^\circ C$.
- (3) $T_{amb} = -55^\circ C$.

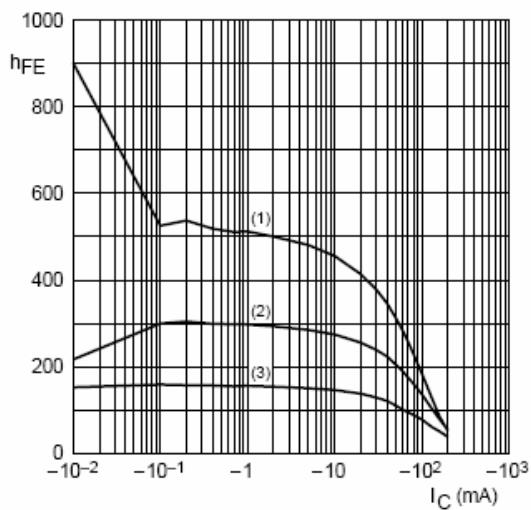
Fig.4 Collector-emitter saturation voltage as a function of collector current; typical values.



BC857A; $I_C/I_B = 20$.

- (1) $T_{amb} = -55^\circ C$.
- (2) $T_{amb} = 25^\circ C$.
- (3) $T_{amb} = 150^\circ C$.

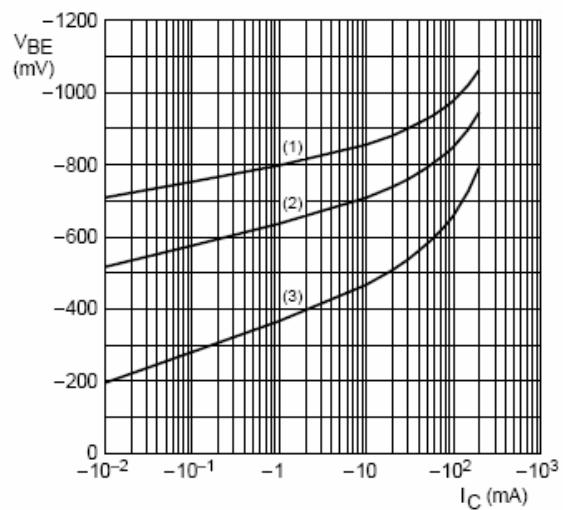
Fig.5 Base-emitter saturation voltage as a function of collector current; typical values.



BC857B; $V_{CE} = -5$ V.

- (1) $T_{amb} = 150$ °C.
- (2) $T_{amb} = 25$ °C.
- (3) $T_{amb} = -55$ °C.

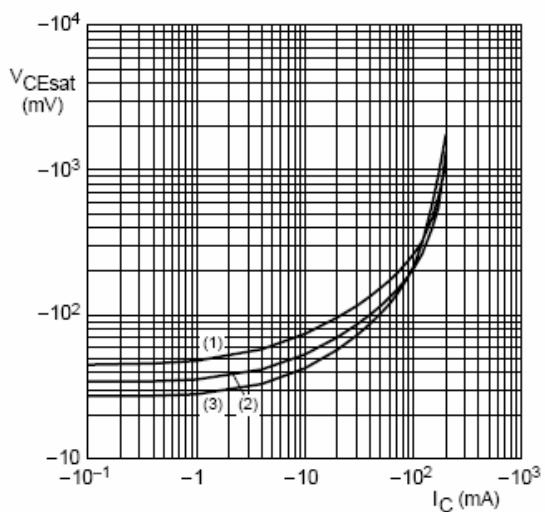
Fig.6 DC current gain as a function of collector current; typical values.



BC857B; $V_{CE} = -5$ V.

- (1) $T_{amb} = -55$ °C.
- (2) $T_{amb} = 25$ °C.
- (3) $T_{amb} = 150$ °C.

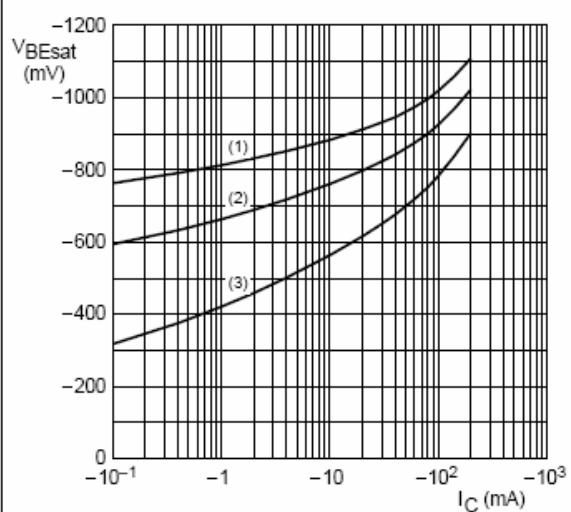
Fig.7 Base-emitter voltage as a function of collector current; typical values.



BC857B; $I_c/I_b = 20$.

- (1) $T_{amb} = 150$ °C.
- (2) $T_{amb} = 25$ °C.
- (3) $T_{amb} = -55$ °C.

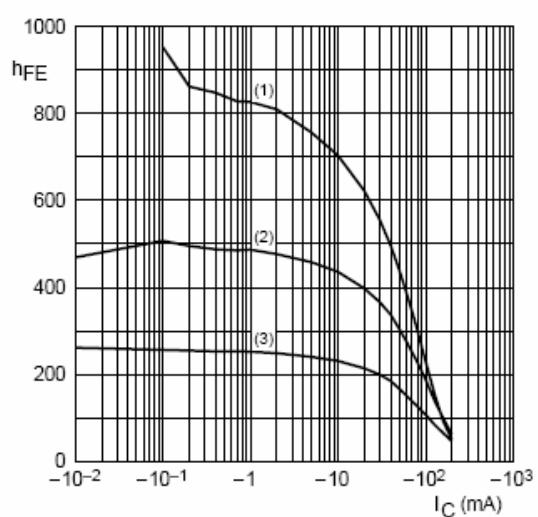
Fig.8 Collector-emitter saturation voltage as a function of collector current; typical values.



BC857B; $I_c/I_b = 20$.

- (1) $T_{amb} = -55$ °C.
- (2) $T_{amb} = 25$ °C.
- (3) $T_{amb} = 150$ °C.

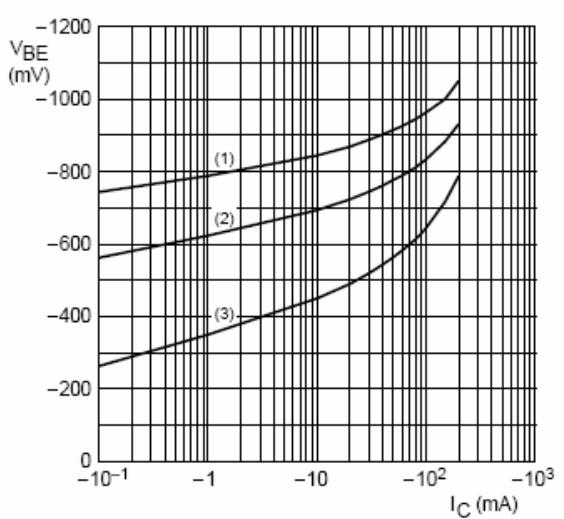
Fig.9 Base-emitter saturation voltage as a function of collector current; typical values.



BC857C; $V_{CE} = -5$ V.

- (1) $T_{amb} = 150$ °C.
- (2) $T_{amb} = 25$ °C.
- (3) $T_{amb} = -55$ °C.

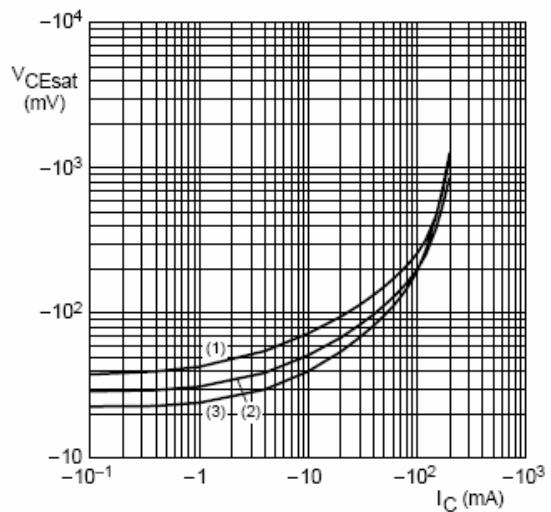
Fig.10 DC current gain as a function of collector current; typical values.



BC857C; $V_{CE} = -5$ V.

- (1) $T_{amb} = -55$ °C.
- (2) $T_{amb} = 25$ °C.
- (3) $T_{amb} = 150$ °C.

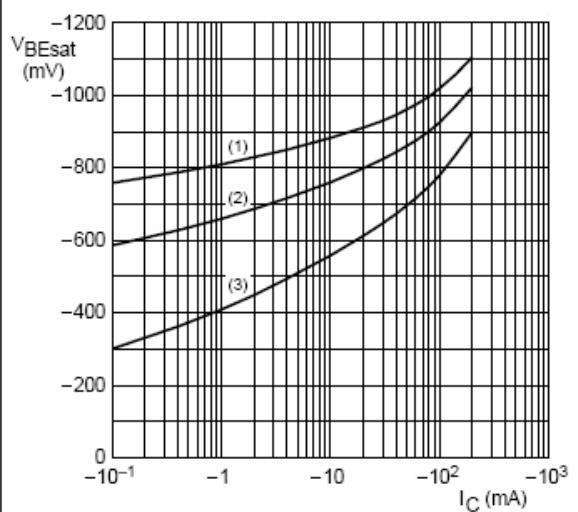
Fig.11 Base-emitter voltage as a function of collector current; typical values.



BC857C; $I_C/I_B = 20$.

- (1) $T_{amb} = 150$ °C.
- (2) $T_{amb} = 25$ °C.
- (3) $T_{amb} = -55$ °C.

Fig.12 Collector-emitter saturation voltage as a function of collector current; typical values.



BC857C; $I_C/I_B = 20$.

- (1) $T_{amb} = -55$ °C.
- (2) $T_{amb} = 25$ °C.
- (3) $T_{amb} = 150$ °C.

Fig.13 Base-emitter saturation voltage as a function of collector current; typical values.